

# KAF16200

## Charge Trapping

### Maximum Practical Exposure Limit

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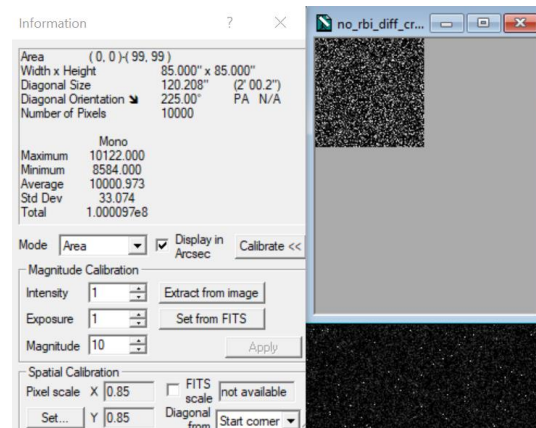
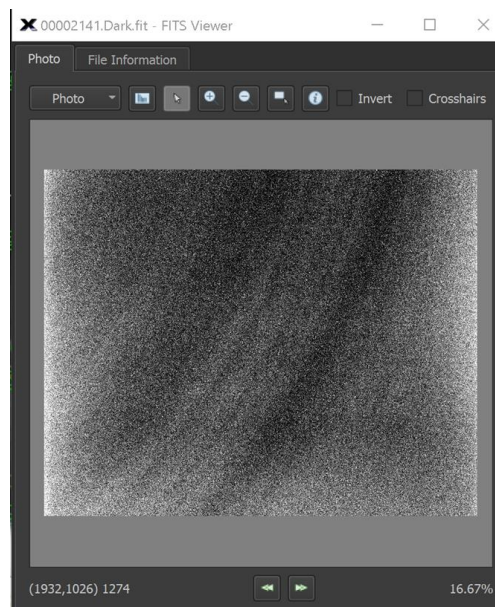
# KAF16200 #1 (Striebeck sensor)

- 450 second darks binned 2x2 at -30C sensor temp
- Frame differenced identical pairs: one taken with RBI flooding, another taken w/o RBI flooding\*
- 10,000 DN added to Minuend prior to subtraction
- A 100 x 100 region located at 2050X, 850Y was cropped & examined for both data sets

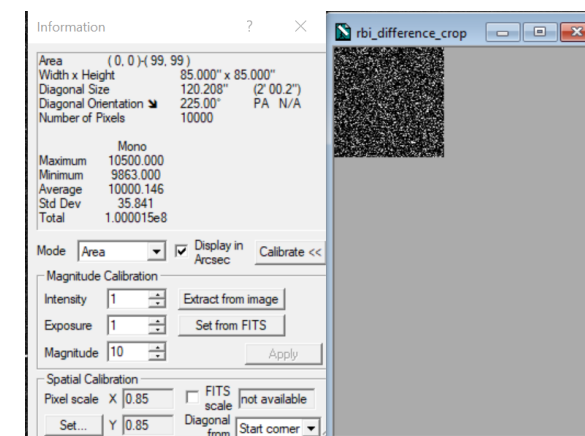
\*because FLI camera flashes LED upon power-up charge trapping is avoided by using a warm, room temperature camera when power was applied. Any charge trapped during the power-on transient is allowed to decay over the next ten minutes with the cooler OFF. Only then is the cooler enabled allowing the sensor to be cooled down.

# Empirical Results

sensor	StDev (no flood)	StDev (with flood)
KAF16200 #1 (M.S.)	33.074 DN	35.841 DN



Mark Striebeck data



Mark Striebeck data

Light-flooded dark:  
450 sec, 2x2 binning, -30C

# Detailed Analysis -30C Sensor #1 (M.S.)

Parameter Name	value	units	notes
full well	41000	e-	datasheet
offset	1000	DN	guess, camera design spec
Full well	65535	DN	camera design spec
gain	1.574024	DN/e-	calculated, camera design spec
Kadc	0.635314	e-/DN	calculated, camera design spec
std RBI	35.841	DN	measured
std noRBI	33.074	DN	measured
total noise RBI flood	16.10103	e-	calculated
total noise noRBI flood	14.858	e-	calculated
read noise	7.4	e-	guess, needs to be measured
total dark shot w/light flood (noise)	14.29976	e-	calculated
total dark shot noLight flood (noise)	12.8841	e-	calculated
delta (trap leakage)	1.41566	e-	calculated
total dark signal w/light flood	204.4832	e-	calculated
total dark signal noLight flood	166.0001	e-	calculated
Trap leakage RBI	38.4831	e-	calculated
Trapped leakage as % of thermally generated	23.18	percentage	calculated
Noise due to Trap Leakage	6.203475	e-	calculated
Noise due to thermally generated dark signal	12.8841	e-	calculated
exp time	450	sec	setting
binning	2 x&y		setting
measured dark signal/pixel/sec noLight flood	0.092222	e-/pix/sec	calculated
dark current spec	112	e-/sec/pixel	datasheet
dark current temperature	60	C	datasheet
operating temp	-30	C	measured
spread	90	C	calculated
doubling temperature	11	C	datasheet
number of doublings to reach op temp	8.181818	dimensionless	calculated
dark temp scaling factor to reach op temp	290.384	dimensionless	calculated
Spec dark signal at op temp	0.385696	e-/pix/sec	calculated from spec
Actual Device Dark Signal % of spec	23.91	percentage	calculated
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, no light flood)			
Total dark signal permissible	54.76	e-	definition of M.P.E.L.
time to reach max dark signal @ -30C	593.7829	seconds	calculated from measured data
time to reach max dark signal @ -30C	9.896381	minutes	calculated from measured data

Noise Component	Value	unit
Read Noise	7.4	e-
Thermal Dark Shot	12.88	e-
Trap Leakage Dark Shot	6.20	e-

With 450 sec dark, 2x2 binning& and -30C operation, this sensor is exceeding the practical exposure limit:  
(Read Noise < Total Dark Shot Noise)

This is equivalent to a 1x1 binned 30 minute exposure

***Practical exposure limit at -30C for this sensor with 1x1 binning and no light flood is 9.9 minutes (594 seconds)***

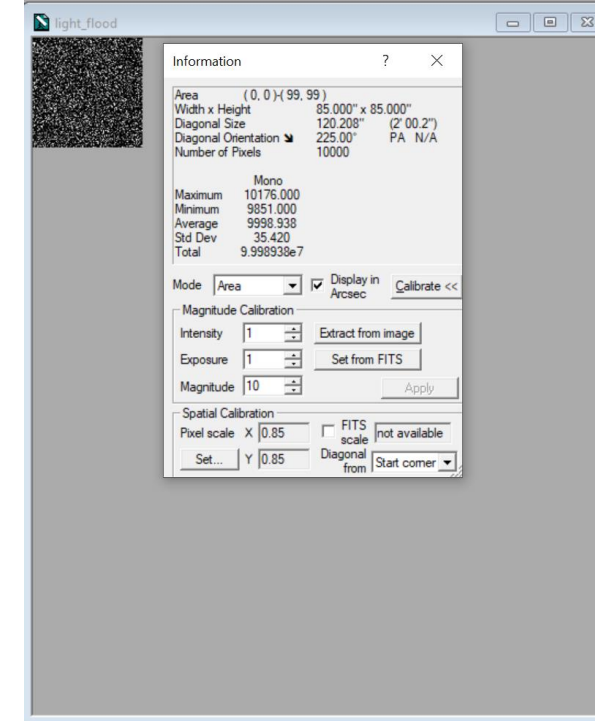
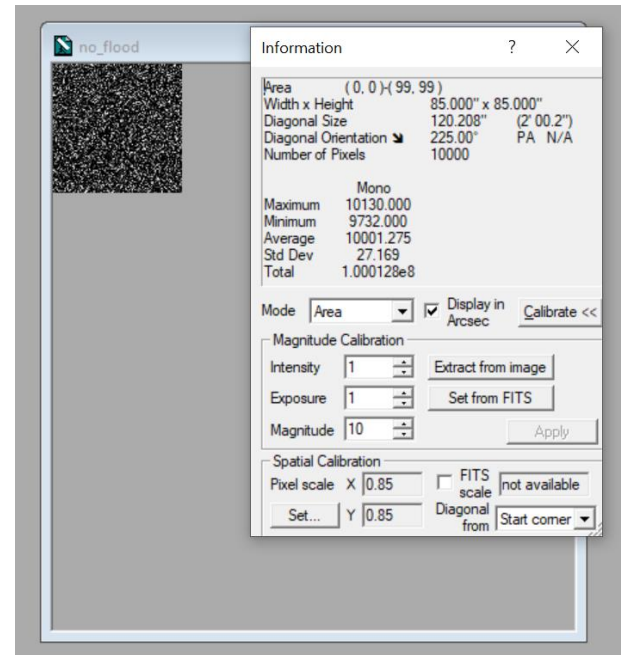
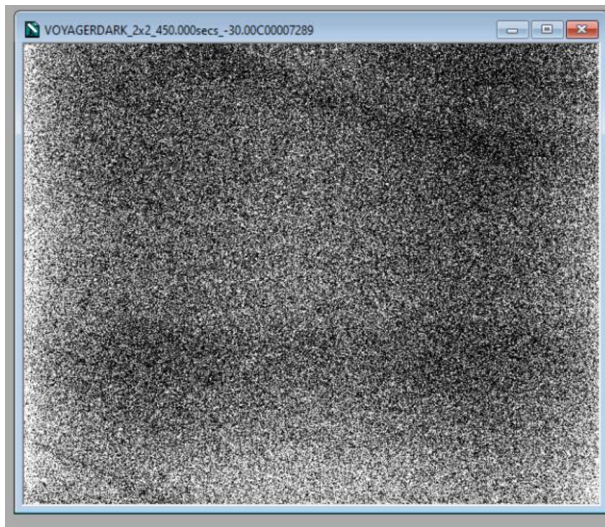
This is your measured dark signal/pixel/sec

This what ON-Semi specifies for dark signal/pixel/sec

This is your measured dark signal vs ON-Semi Spec ratio for dark signal/pixel/sec

# Empirical Results (Sensor #2: B.L.)

sensor	StDev (no flood)	StDev (with flood)
KAF16200 #2 (B.L.)	27.169 DN	35.420



# FLI Test Data for Sensor #2 (B.L.)

```
Finger Lakes Instrumentation Quality Assurance Test Summary
FLI Library Version: Software Development Library for Windows 1.98
FLITest_SCX Version: 3.31 SCX, Tester SN: 8

Serial Number: ML6554016
Model: MICROLINE ML16200
Sensor designation: 4H2407 743
Sensor Type: Single Channel
Lab ambient temp: 24.0
CCD Test Temp: -25

Basic Functions
  CCD temp sensor: OK.
  Base temp sensor: OK.

CCD Chamber
  Desiccant installed: OK.
  Purged: OK.
  Noble Gas Back-fill: OK.
  Window clean on both surfaces: OK.
  CCD free of dust: Yes

Performance
  Cooler can achieve dT greater than: -45.0C (measured -58.2)
  Cooler is rate limited: Yes (-9.67 C/min)
  Cooler test time: 772.56
  Cooler Tests: Pass
  Noise distribution is random: Yes
  Bias frame histogram is Gaussian: Yes
  Standard test target appearance OK: Yes

Specific Tests
  Amplifier Glow Test: Pass
  Amplifier Glow Auxiliary Test: Pass
  Power Supply voltage: 11.9
  AUX Connector Pin 4 voltage: -0.0
  Camera Current: 1117.4 mA (Pass)
  Cooler Current: 3791.9 mA (Pass)
  External Trigger: Working
  AUX Pin 1: Working OK.
  AUX Pin 2: Working OK.
  AUX Pin 3: Working OK.

Gain and Noise Measurement
12 MHz Focus Mode Main
  Conversion factor (gain): 0.64
  Bias: 982.3
  Readout noise: 12.3 (e-)
  Saturation: 41315.8 (e-)
  Horizontal Binning Test: Pass
  Bias Drift Test: Pass
  100s Dark Current Growth: 1.1 ADU (Pass) @ -25.0 C
  Maximum Linearity Error: 0.661 (%) (Pass)

2 MHz Main
  Conversion factor (gain): 0.66
  Bias: 1004.3
  Readout noise: 6.7 (e-)
  Saturation: 42308.0 (e-)
  Horizontal Binning Test: Pass
  Bias Drift Test: Pass
  100s Dark Current Growth: 1.1 ADU (Pass) @ -25.0 C
  Maximum Linearity Error: 0.614 (%) (Pass)

Camera Passed.
```

# Detailed Analysis -30C Sensor #2 (B.L.)

Parameter Name	value	units	notes
full well	42308e-		FLI provided test data
offset	1004.3DN		FLI provided test data
gain	1.515152DN/e-		calculated from FLI test data
Kadc	0.66e-/DN		FLI provided test data
std RBI	35.42DN		measured from frame differenced identical darks: data input
std noRBI	27.169DN		measured from frame differenced identical darks: data input
total noise, Light flood	16.53018e-		calculated from frame differenced identical darks: data input
total noise, no Light flood	12.67951e-		calculated from frame differenced identical darks: data input
read noise	6.761e-		FLI provided test data
total dark shot w/light flood (noise)	15.08428e-		calculated
thermal dark shot no Light flood (noise)	10.72655e-		calculated
quadrature delta (Trap Leakage Shot Noise)	10.6055e-		calculated
total dark signal w/light flood	227.5356e-		calculated
Thermal dark signal no Light flood	115.0589e-		calculated
Trap leakage Light Flood (Signal)	112.4767e-		calculated
Trapped leakage as % of thermally generated	97.76%percentage		calculated
Noise due to thermally generated dark signal	10.72655e-		calculated
exp time	450sec		setting
binning	2x&y		setting
measured dark signal/pixel/sec noLight flood	0.063922e-/pix/sec		calculated from dark shot noise measurements
dark current spec	112e-/sec/pixel		On Semi datasheet
dark current temperature	60C		On Semi datasheet
operating temp	-30C		measured
spread	90C		calculated
doubling temperature	11C		On Semi datasheet
number of doublings to reach op temp	8.181818dimensionless		calculated
dark temp scaling factor to reach op temp	290.384dimensionless		calculated
Inferred Data Sheet Spec dark signal at op temp	0.385696e-/pix/sec		calculated from On Semi Datasheet Spec
Actual Device Measured Dark Signal % of spec	16.57%percentage		calculated
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, no light flood)			
Total dark signal permissible	45.71112e-		definition of M.P.E.L.
time to reach max dark signal @ -30C	715.1119seconds		calculated from measured data
time to reach max dark signal @ -30C	11.91853minutes		calculated from measured data
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, with light flood)			
time to reach max dark signal @ -30C	361.6138seconds		calculated from measured data
time to reach max dark signal @ -30C	6.026897minutes		calculated from measured data
FLI Dark Signal Test Data Reconciliation			
exposure time	100seconds		FLI test conditions measurement specification*
100s total dark signal (no light flood)	6.392163electrons		calculated from shot noise measurements
100s total dark signal (no light flood)	9.685096DN		calculated from shot noise measurements

\*there are different ways to measure this. In this case a shot noise analysis is made based on frame-differenced identical darks of known duration.

Noise Component	Value	unit
Read Noise	6.761	e-
Thermal Dark Shot	10.72	e-
Trap Leakage Dark Shot	10.61	e-

With 450 sec dark, 2x2 binning& and -30C operation, this sensor is exceeding the practical exposure limit:  
(Read Noise < Total Dark Shot Noise)

This is equivalent to a 1x1 binned 30 minute exposure

**Practical exposure limit at -30C for this sensor with 1x1 binning and no light flood is 11.91 minutes (715.1 seconds)**

This is your measured dark signal/pixel/sec

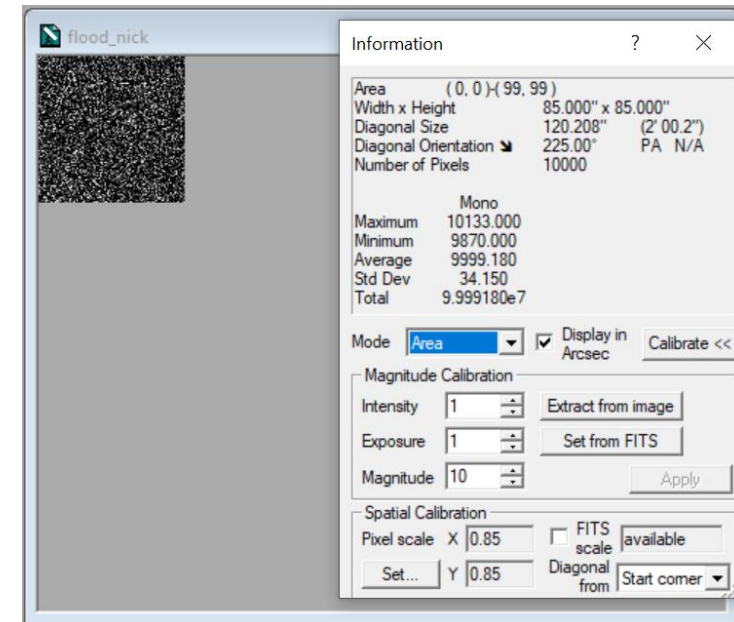
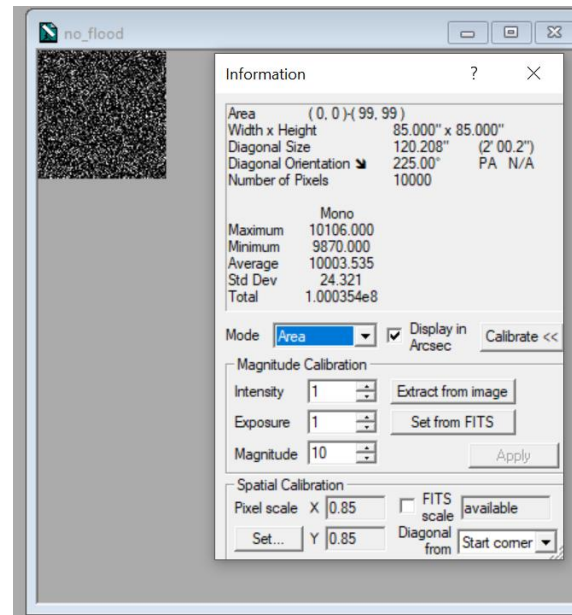
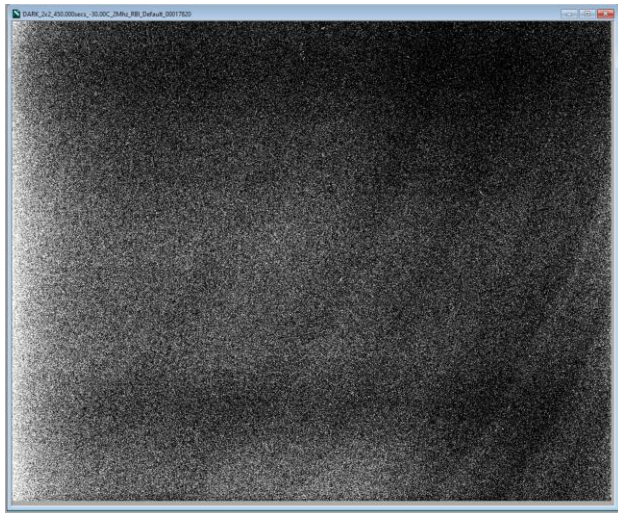
This what ON-Semi specifies for dark signal/pixel/sec

This is your measured dark signal as a percentage of ON-Semi Spec



# Empirical Results (Sensor #3: N.S.)

sensor	StDev (no flood)	StDev (with flood)
KAF16200 #3 (N.S.)	24.321 DN	34.150





# FLI Test Data for Sensor #3 (N.S.)

```
Finger Lakes Instrumentation Quality Assurance Test Summary
FLI Library Version: Software Development Library for Windows 1.98
FLITest_SCM Version: 3.31 SCM, Tester SN: 4

Serial Number: ML5984410
Model: MICROLINE ML16200
Sensor designation: 4H2408 1226
Sensor Type: Single Channel
Lab ambient temp: 23.0
CCD Test Temp: -25

Basic Functions
  CCD temp sensor: OK.
  Base temp sensor: OK.

CCD Chamber
  Desiccant installed: OK.
  Purged: OK.
  Noble Gas Back-fill: OK.
  Window clean on both surfaces: OK.
  CCD free of dust: Yes

Performance
  Cooler can achieve dT greater than: -45.0C (measured -59.6)
  Cooler is rate limited: Yes (-9.89 C/min)
  Cooler test time: 782.56
  Cooler Tests: Pass
  Noise distribution is random: Yes
  Bias frame histogram is Gaussian: Yes
  Standard test target appearance OK: Yes

Specific Tests
  Amplifier Glow Test: Pass
  Amplifier Glow Auxiliary Test: Pass
  Power Supply voltage: 11.8
  AUX Connector Pin 4 voltage: -0.0
  Camera Current: 950.0 mA (Pass)
  Cooler Current: 3574.2 mA (Pass)
  External Trigger: Working
  AUX Pin 1: Working OK.
  AUX Pin 2: Working OK.
  AUX Pin 3: Working OK.

Gain and Noise Measurement
12 MHz Focus Mode Main
  Conversion factor (gain): 0.61
  Bias: 996.5
  Readout noise: 11.7 (e-)
  Saturation: 39196.9 (e-)
  Horizontal Binning Test: Pass
  Bias Drift Test: Pass
  100s Dark Current Growth: 0.5 ADD (Pass) @ -25.0 C
  Maximum Linearity Error: 0.294 (%) (Pass)

2 MHz Main
  Conversion factor (gain): 0.61
  Bias: 994.1
  Readout noise: 6.0 (e-)
  Saturation: 39662.4 (e-)
  Horizontal Binning Test: Pass
  Bias Drift Test: Pass
  100s Dark Current Growth: 0.3 ADD (Pass) @ -25.0 C
  Maximum Linearity Error: 0.285 (%) (Pass)

Camera Passed.
```

# Detailed Analysis -30C Sensor #3 (N.S.)

Parameter Name	value	units	notes
full well	39662.4 e-		FLI provided test data
offset	994.1 DN		FLI provided test data
gain	1.639344 DN/e-		calculated from FLI test data
Kadc	0.61 e-/DN		FLI provided test data
std RBI	34.15 DN		measured from frame differenced identical darks: data input
std noRBI	24.321 DN		measured from frame differenced identical darks: data input
total noise, Light flood	14.73009 e-		calculated from frame differenced identical darks: data input
total noise, no Light flood	10.4905 e-		calculated from frame differenced identical darks: data input
read noise	6 e-		FLI provided test data
total dark shot w/light flood (noise)	13.45272 e-		calculated
thermal dark shot no Light flood (noise)	8.605268 e-		calculated
quadrature delta (Trap Leakage Shot Noise)	10.34046 e-		calculated
total dark signal w/light flood	180.9757 e-		calculated
Thermal dark signal no Light flood	74.05063 e-		calculated
Trap leakage Light Flood (Signal)	106.9251 e-		calculated
Trapped leakage as % of thermally generated	144.39 percentage		calculated
Noise due to thermally generated dark signal	8.605268 e-		calculated
exp time	450 sec		setting
binning	2x2		setting
measured dark signal/pixel/sec noLight flood	0.041139 e-/pix/sec		calculated from dark shot noise measurements
dark current spec	112 e-/sec/pixel		On Semi datasheet
dark current temperature	60 C		On Semi datasheet
operating temp	-30 C		measured
spread	90 C		calculated
doubling temperature	11 C		On Semi datasheet
number of doublings to reach op temp	8.181818 dimensionless		calculated
dark temp scaling factor to reach op temp	290.384 dimensionless		calculated
Inferred Data Sheet Spec dark signal at op temp	0.385696 e-/pix/sec		calculated from On Semi Datasheet Spec
Actual Device Measured Dark Signal % of spec	10.67 percentage		calculated
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, no light flood)			
Total dark signal permissible	36 e-		definition of M.P.E.L.
time to reach max dark signal @ -30C	875.077 seconds		calculated from measured data
time to reach max dark signal @ -30C	14.58462 minutes		calculated from measured data
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, with light flood)			
time to reach max dark signal @ -30C	358.0591 seconds		calculated from measured data
time to reach max dark signal @ -30C	5.967652 minutes		calculated from measured data
FLI Dark Signal Test Data Reconciliation			
exposure time	100 seconds		FLI test conditions measurement specification*
100s total dark signal (no light flood)	4.113924 electrons		calculated from shot noise measurements
100s total dark signal (no light flood)	6.744137 DN		calculated from shot noise measurements

Noise Component	Value	unit
Read Noise	6.00	e-
Thermal Dark Shot	8.605	e-
Trap Leakage Dark Shot	10.34	e-

With 450 sec dark, 2x2 binning& and -30C operation, this sensor is exceeding the practical exposure limit:  
(Read Noise < Total Dark Shot Noise)

This is equivalent to a 1x1 binned 30 minute exposure

**Practical exposure limit at -30C for this sensor with 1x1 binning and no light flood is 14.58 minutes (875.1 seconds)**

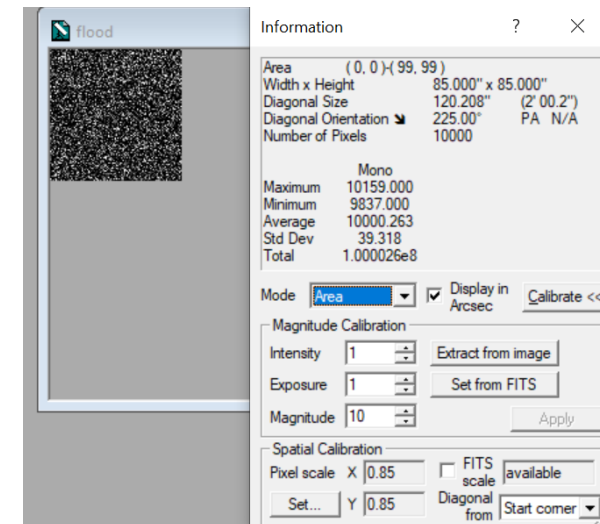
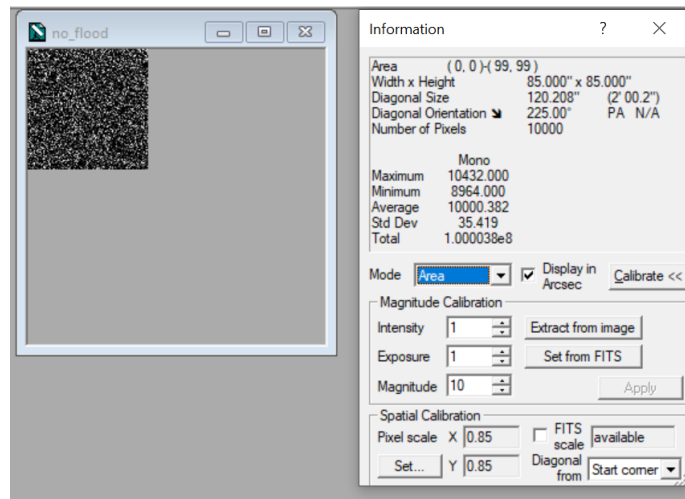
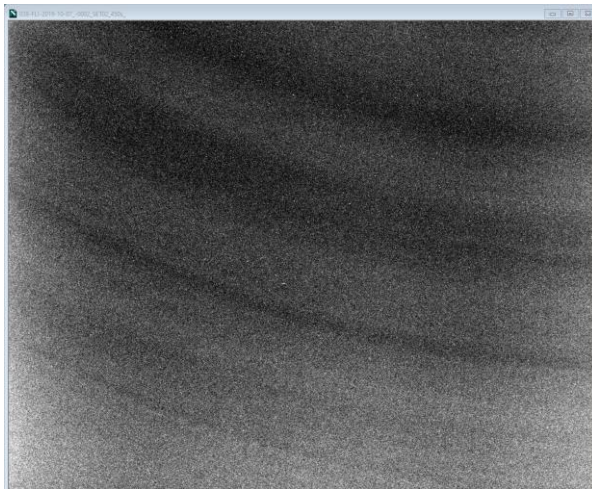
This is your measured dark signal/pixel/sec

This what ON-Semi specifies for dark signal/pixel/sec

This is your measured dark signal vs ON-Semi Spec ratio for dark signal/pixel/sec

# Empirical Results (Sensor #4: B.K.)

sensor	StDev (no flood)	StDev (with flood)
KAF16200 #4 (B.K.)	35.419	39.318



# FLI Test Data for Sensor #4 (B.K.)

2019-05-10

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FLI ML16200 Returned Today  
New PCB's and Sensor  
Starting Diagnostics

Things to do:  
New DTC / PTC  
Establish Gain and Bias  
Dark Current Measurements

FLI Measurements Documented

2 MHz

Gain 0.64 e-/ADU

Bias: 1002.3 ADU

Read Noise 6.8 e-

Saturation 41415.4 e-

64711.5625 ADU

100s Dark Current Growth: 2.9 ADU @ -25C

Max Linearity Error: 0.157%

# Detailed Analysis -30C Sensor #4 (B.K.)

Noise Component	Value	unit
Read Noise	6.8	e-
Thermal Dark Shot	14.51	e-
Trap Leakage Dark Shot	7.73	e-

Parameter Name	value	units	notes
full well	41415 e-		FLI provided test data
offset	1002.3 DN		FLI provided test data
gain	1.5625 DN/e-		calculated from FLI test data
Kadc	0.64 e-/DN		FLI provided test data
std RBI	39.318 DN		measured from frame differenced identical darks: data input
std noRBI	35.419 DN		measured from frame differenced identical darks: data input
total noise, Light flood	17.7933 e-		calculated from frame differenced identical darks: data input
total noise, no Light flood	16.02881 e-		calculated from frame differenced identical darks: data input
read noise	6.8 e-		FLI provided test data
total dark shot w/light flood (noise)	16.44267 e-		calculated
thermal dark shot no Light flood (noise)	14.51491 e-		calculated
quadrature delta (Trap Leakage Shot Noise)	7.725195 e-		calculated
total dark signal w/light flood	270.3614 e-		calculated
Thermal dark signal no Light flood	210.6827 e-		calculated
Trap leakage Light Flood (Signal)	59.67863 e-		calculated
Trapped leakage as % of thermally generated	28.33% percentage		calculated
Noise due to thermally generated dark signal	14.51491 e-		calculated
exp time	450 sec		setting
binning	2x8y		setting
measured dark signal/pixel/sec noLight flood	0.117046 e-/pix/sec		calculated from dark shot noise measurements
dark current spec	112 e-/sec/pixel		On Semi datasheet
dark current temperature	60 C		On Semi datasheet
operating temp	-30 C		measured
spread	90 C		calculated
doubling temperature	11 C		On Semi datasheet
number of doublings to reach op temp	8.181818 dimensionless		calculated
dark temp scaling factor to reach op temp	290.384 dimensionless		calculated
Inferred Data Sheet Spec dark signal at op temp	0.385696 e-/pix/sec		calculated from On Semi Datasheet Spec
Actual Device Measured Dark Signal % of spec	30.35% percentage		calculated
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, no light flood)			
Total dark signal permissible	46.74 e-		definition of M.P.E.L.
time to reach max dark signal @ -30C	395.0585 seconds		calculated from measured data
time to reach max dark signal @ -30C	6.584308 minutes		calculated from measured data
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, with light flood)			
time to reach max dark signal @ -30C	307.8546 seconds		calculated from measured data
time to reach max dark signal @ -30C	5.130911 minutes		calculated from measured data
FLI Dark Signal Test Data Reconciliation			
exposure time	100 seconds		FLI test conditions measurement specification*
100s total dark signal (no light flood)	11.7046 electrons		calculated from shot noise measurements
100s total dark signal (no light flood)	18.28843 DN		calculated from shot noise measurements

\*there are different ways to measure this. In this case a shot noise analysis is made based on frame-differenced identical darks of known duration.

With 450 sec dark, 2x2 binning& and -30C operation, this sensor is exceeding the practical exposure limit:  
(Read Noise < Total Dark Shot Noise)

This is equivalent to a 1x1 binned 30 minute exposure

**Practical exposure limit at -30C for this sensor with 1x1 binning and no light flood is 6.58 minutes (395.05 seconds)**

This is your measured dark signal/pixel/sec

This what ON-Semi specifies for dark signal/pixel/sec

This is your measured dark signal vs ON-Semi Spec ratio for dark signal/pixel/sec

# Empirical Results (Sensor #5: T.K.)

sensor	StDev (no flood)	StDev (with flood)
KAF16200 #5 (T.K.)	36.453	48.646



Information ? X

Area (0, 0)-(99, 99)  
 Width x Height 85,000" x 85,000"  
 Diagonal Size 120.208" (2' 00.2")  
 Diagonal Orientation 225.00° PA N/A  
 Number of Pixels 10000

Mono  
 Maximum 10173.000  
 Minimum 9858.000  
 Average 10000.812  
 Std Dev 36.453  
 Total 1.000081e8

Mode Area ☒ Display in Arcsec Calibrate <<

Magnitude Calibration  
 Intensity 1 Extract from image  
 Exposure 1 Set from FITS  
 Magnitude 10 Apply

Spatial Calibration  
 Pixel scale X 0.85 ☐ FITS scale not available  
 Set... Y 0.85 Diagonal from Start corner

Information ? X

Area (0, 0)-(99, 99)  
 Width x Height 85,000" x 85,000"  
 Diagonal Size 120.208" (2' 00.2")  
 Diagonal Orientation 225.00° PA N/A  
 Number of Pixels 10000

Mono  
 Maximum 10197.000  
 Minimum 9520.000  
 Average 10002.299  
 Std Dev 48.646  
 Total 1.000230e8

Mode Area ☒ Display in Arcsec Calibrate <<

Magnitude Calibration  
 Intensity 1 Extract from image  
 Exposure 1 Set from FITS  
 Magnitude 10 Apply

Spatial Calibration  
 Pixel scale X 0.85 ☐ FITS scale not available  
 Set... Y 0.85 Diagonal from Start corner



# FLI Test Data for Sensor #5 (T.K.)

- Still need this

# Detailed Analysis -30C Sensor #5 (T.K.)

Noise Component	Value	unit
Read Noise	6.44	e-
Thermal Dark Shot	15.829	e-
Trap Leakage Dark Shot	15.103	e-

Parameter Name	value	units	notes
full well	42019 e-		FLI provided test data
offset	1000 DN		FLI provided test data
gain	1.508296 DN/e-		calculated from FLI test data
Kadc	0.663 e-/DN		FLI provided test data
std RBI	48.646 DN		measured from frame differenced identical darks: data input
std noRBI	36.453 DN		measured from frame differenced identical darks: data input
total noise, Light flood	22.80582 e-		calculated from frame differenced identical darks: data input
total noise, no Light flood	17.0896 e-		calculated from frame differenced identical darks: data input
read noise	6.44 e-		FLI provided test data
total dark shot w/light flood (noise)	21.87765 e-		calculated
thermal dark shot no Light flood (noise)	15.82974 e-		calculated
quadrature delta (Trap Leakage Shot Noise)	15.10136 e-		calculated
total dark signal w/light flood	478.6318 e-		calculated
Thermal dark signal no Light flood	250.5807 e-		calculated
Trap leakage Light Flood (Signal)	228.0511 e-		calculated
Trapped leakage as % of thermally generated	91.01% percentage		calculated
Noise due to thermally generated dark signal	15.82974 e-		calculated
exp time	450 sec		setting
binning	2 x&y		setting
measured dark signal/pixel/sec noLight flood	0.139212 e-/pix/sec		calculated from dark shot noise measurements
dark current spec	112 e-/sec/pixel		On Semi datasheet
dark current temperature	60 C		On Semi datasheet
operating temp	-30 C		measured
spread	90 C		calculated
doubling temperature	11 C		On Semi datasheet
number of doublings to reach op temp	8.181818 dimensionless		calculated
dark temp scaling factor to reach op temp	290.384 dimensionless		calculated
Inferred Data Sheet Spec dark signal at op temp	0.385696 e-/pix/sec		calculated from On Semi Datasheet Spec
Actual Device Measured Dark Signal % of spec	36.09% percentage		calculated
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, no light flood)			
Total dark signal permissible	41.4736 e-		definition of M.P.E.L.
time to reach max dark signal @ -30C	297.9179 seconds		calculated from measured data
time to reach max dark signal @ -30C	4.965299 minutes		calculated from measured data
Maximum Practical Exposure Limit Calculation (M.P.E.L.) (1x1 binning, with light flood)			
time to reach max dark signal @ -30C	155.9706 seconds		calculated from measured data
time to reach max dark signal @ -30C	2.59951 minutes		calculated from measured data
FLI Dark Signal Test Data Reconciliation			
exposure time	100 seconds		FLI test conditions measurement specification*
100s total dark signal (no light flood)	13.92115 electrons		calculated from shot noise measurements
100s total dark signal (no light flood)	20.99721 DN		calculated from shot noise measurements

With 450 sec dark, 2x2 binning& and -30C operation, this sensor is exceeding the practical exposure limit:  
(Read Noise < Total Dark Shot Noise)

This is equivalent to a 1x1 binned 30 minute exposure

**Practical exposure limit at -30C for this sensor with 1x1 binning and no light flood is 4.96 minutes (297.9 seconds)**

This is your measured dark signal/pixel/sec

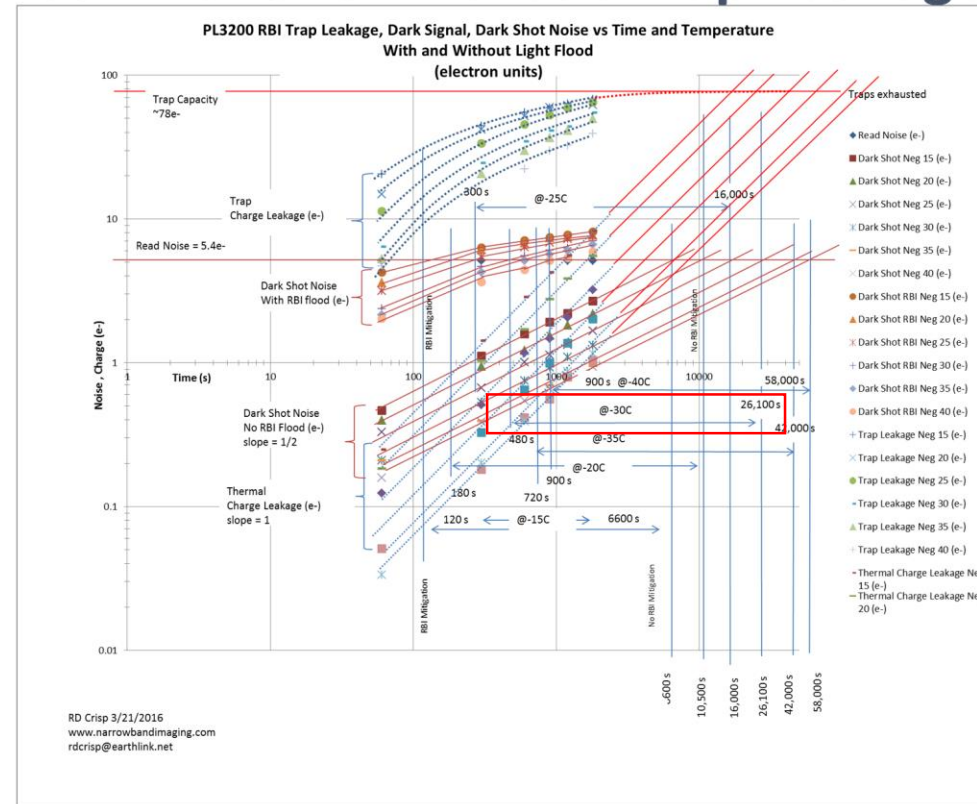
This what ON-Semi specifies for dark signal/pixel/sec

This is your measured dark signal vs ON-Semi Spec ratio for dark signal/pixel/sec

M.P.E.L. From KAF3200  
with(trap leakage case)/without light flood

## KAF3200 With and Without Trap Leakage

With light flood:  
Max practical exposure  
limit for -30C operation  
is 480 sec



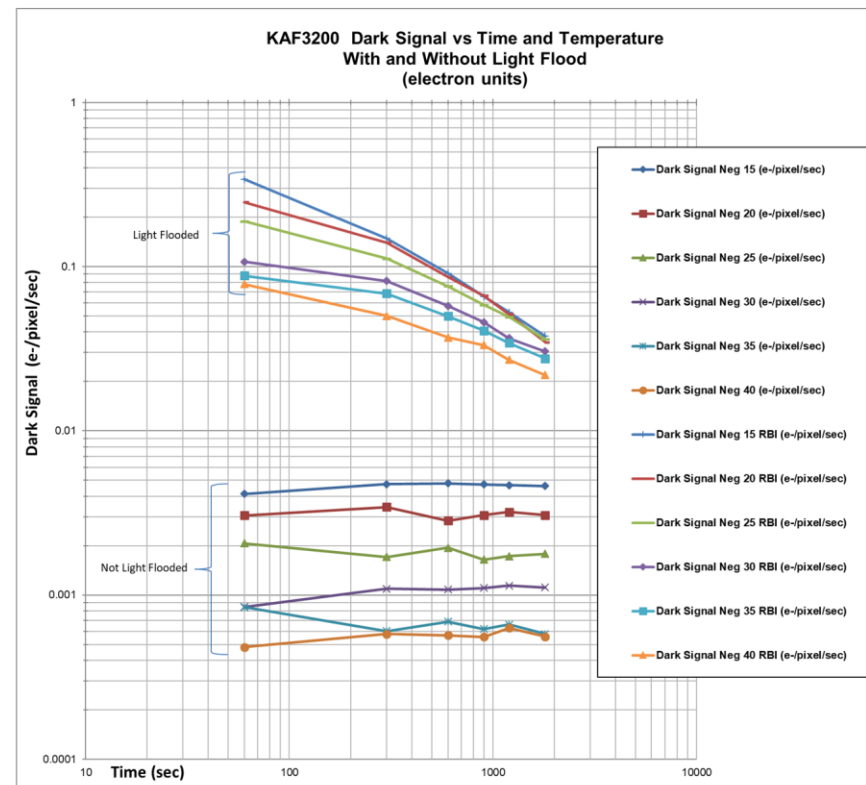
For no light flood:  
Max practical exposure  
limit for -30C operation  
is 26,100 sec

# Dark Signal From KAF3200

## Dark Signal With and Without Trap Leakage

Dark signal component due to trap leakage is over an order of magnitude larger than thermally generated dark signal component for the KAF3200

The opposite is true for the KAF16200!



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